

**In the United States Patent and Trademark Office**

Serial No. 10/550,855	§	Filing date: 09/18/2006
	§	
Title: FORMATION OF THIN SEMI-CONDUCTOR LAYERS BY LOW-ENERGY PLASMA ENHANCED CHEMICAL VAPOR DEPOSITION AND SEMICONDUCTOR HETERO-STRUCTURE DEVICES	§	Examiner: McCall Shepard, Sonya D
	§	
	§	GA No.: 2813
	§	
	§	Confirmation No. 3611
	§	
Applicant: VON KAENEL, Hans	§	Atty docket No: PUS-E005-013

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**CERTIFICATE OF TRANSMISSION UNDER 37 CFR §1.8.** I hereby certify that this correspondence is being facsimile transmitted to the Patent and Trademark Office, as \_\_\_\_\_ pages, total,

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**AMENDMENT**

***Via facsimile to 001-571-273-8300, to:***

Commissioner for Patents  
P. O. Box 1450  
Alexandria, Virginia 22313-1450  
U.S.A.

Dear Sir,

Applicant thanks the Office for the Official Action dated June 2, 2009, and in response thereto, Applicant requests that the amendments which begin on page 3 be entered and considered in light of the remarks which begin on page 9.

The Undersigned authorizes the Commissioner to charge any fee or credit any overpayment of any fee under 37 CFR §1.16 which may be required in this application, to the deposit account of MOETTELI & ASSOCIES SARL, No. 50-2621.

If the Examiner has further questions, she is invited to contact the undersigned by email at [moetteli@patentinfo.net](mailto:moetteli@patentinfo.net) (preferred) or by phone at 011-4171 230 1000.

Respectfully submitted,

A handwritten signature in black ink, appearing to read 'John Moetteli', with a long horizontal stroke extending to the right.

/s/John Moetteli/

John Moetteli

U.S. Reg. No. 35,289

Date: August 26, 2009